



THE UNITED STATES PATENT AND TRADEMARK OFFICE

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In re the Application of:

Shigeo OHSAKA et al.

Serial Number: 09/456,531

Group Art Unit: 2881

Filed: December 8, 1999

Examiner: J. Menefee

For: **ELECTRODE STRUCTURE, PROCESS FOR FABRICATING ELECTRODE
STRUCTURE AND SEMICONDUCTOR LIGHT-EMITTING DEVICE**

AMENDMENT UNDER 37 CFR §1.111

Commissioner for Patents
Washington, D.C. 20231

January 24, 2002

Sir:

In response to the Office Action dated October 24, 2001, please amend the above-identified application as follows:

CLEAN VERSION OF AMENDMENTS

IN THE CLAIMS

Please cancel claims 17 and 18 without prejudice or disclaimer and amend claims 13 - 16 as follows:

13. (Amended) A semiconductor light-emitting device including a waveguide, a lower electrode formed below the waveguide, and an upper electrode formed above the waveguide, the upper electrode having an electrode structure, the electrode structure including a conductive film formed on a base substrate through an insulation film, the insulation film comprising a plurality of poles of polyimide, a first film formed

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